

**isc N-Channel MOSFET Transistor IPD031N03L, IIPD031N03L**

- FEATURES

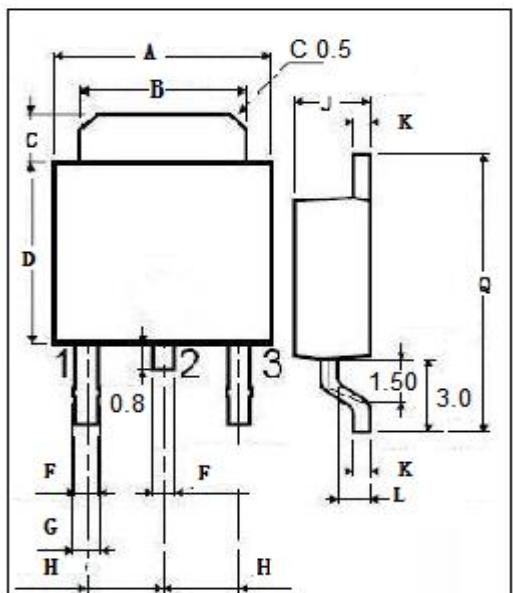
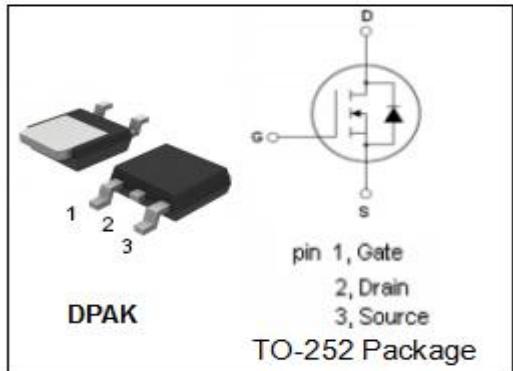
- Static drain-source on-resistance:  
 $R_{DS(on)} \leq 3.1\text{m}\Omega$
  - Enhancement mode:
  - 100% avalanche tested
  - Minimum Lot-to-Lot variations for robust device performance and reliable operation

- DESCRIPTION

- Fast switching

- ABSOLUTE MAXIMUM RATINGS( $T_a=25^\circ\text{C}$ )

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	30	V
V <sub>GS</sub>	Gate-Source Voltage	±20	V
I <sub>D</sub>	Drain Current-Continuous	90	A
I <sub>DM</sub>	Drain Current-Single Pulsed	400	A
P <sub>D</sub>	Total Dissipation @T <sub>C</sub> =25°C	94	W
T <sub>j</sub>	Max. Operating Junction Temperature	175	°C
T <sub>stg</sub>	Storage Temperature	-55~175	°C



DIM	mm	
	MIN	MAX
A	6.40	6.60
B	5.20	5.40
C	1.15	1.35
D	5.70	6.10
F	0.65	
G	0.75	
H	2.10	2.50
J	2.10	2.40
K	0.40	0.60
L	0.90	1.10
Q	9.90	10.1

- THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(j-c)	Channel-to-case thermal resistance	1.6	°C/W
Rth(j-a)	Channel-to-ambient thermal resistance	75	°C/W

**isc N-Channel MOSFET Transistor IPD031N03L, IIPD031N03L****ELECTRICAL CHARACTERISTICS****T<sub>c</sub>=25°C unless otherwise specified**

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> =1mA	30			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; I <sub>D</sub> =250 μA	1		2.2	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =30A			3.1	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = 20V; V <sub>DS</sub> = 0V			0.1	μA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =30V; V <sub>GS</sub> = 0V			25	μA
V <sub>SD</sub>	Diode forward voltage	I <sub>F</sub> =30A, V <sub>GS</sub> = 0V			1.1	V

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